EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	1	"5151632".pn.	USPAT	OR	ON	2006/03/17 15:51
L2	3	(313/310.ccls.) and (anode same (TFT "thin film transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 16:30
L3	2	(313/310.ccls.) and (anode same ("active matrix"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 16:28
L4	99	(313/310.ccls.) and (anode same (active))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 16:28
L5	33	(313/310.ccls.) and (TFT "thin film transistor")	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 16:30
L14	13	("4253044" \| "4410830" \| "4486749" \| "4540983" \| "4617491" \| "4783651" \| "4868555" \| "4972116" \| "5151632" \| "5212472" \| "5235244" \| "5245249" \| "5347292").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/17 16:37
L15	12	("5151632").URPN.	USPAT	OR	ON	2006/03/17 16:43
L16	6	"active matrix vacuum fluorescent"	USPAT	OR	ON	2006/03/17 16:43
S4	1799	313/495.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/16 19:46
S5	716	313/496.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/16 19:46
S6	654	313/497.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/16 19:46
S7	1693	313/309.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/16 19:47
S8	1204	313/351.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17

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S9	45	(S4 S5 S6 S7 S8) and (anode same (TFT "thin film transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 16:25
S10	5	("5150005").URPN.	USPAT	OR	ON	2006/03/17 11:57
S11	2	("5736814").URPN.	USPAT	OR	ON	2006/03/17 12:00
S12	2	("4835445" \| "5150005").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/17 12:00
S13	13	("4253044" \| "4410830" \| "4486749" \| "4540983" \| "4617491" \| "4783651" \| "4868555" \| "4972116" \| "5151632" \| "5212472" \| "5235244" \| "5245249" \| "5347292").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/17 12:04
S14	28	("5541478").URPN.	USPAT	OR	ON	2006/03/17 12:09
S15	1438	315/169.1.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S16	210	345/75.2.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S17	1799	313/495.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S18	716	313/496.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S19	654	313/497.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S20	1693	313/309.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17
S21	1204	313/351.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:17

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S22	45	(S17 S18 S19 S20 S21) and (anode same (TFT "thin film transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:18
S23	143	(S15 S16 S17 S18 S19 S20 S21) and (anode same (TFT "thin film transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:23
S24	10	(S15 S16 S17 S18 S19 S20 S21) and ("addressable anode")	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:21
S25	2	(S15 S16 S17 S18 S19 S20 S21) and ("active matrix anode")	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:22
S26	7	(S15 S16 S17 S18 S19 S20 S21) and ("active anode")	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:22
S27	309	(S15 S16 S17 S18 S19 S20 S21) and (anode same (TFT "transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:23
S28	221	(S15 S16 S17 S18 S19 S20 S21) and (anode with (TFT "transistor"))	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:23
S29	166	(S15 S16 S17 S18 S19 S20 S21) and (anode with (TFT "transistor")) not oled	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:24
S30	91	(S15 S16 S17 S18 S19 S20 S21) and (anode with (TFT "transistor")) not (oled "electroluminescent" "EL element")	US-PGPUB; USPAT; USOCR; EPO; JPO	OR	ON	2006/03/17 12:24
S31	12	("4041348" \| "4100456" \| "4190855" \| "4970575" \| "5001542" \| "5347292" \| "5424605" \| "5469333" \| "5903097" \| "6063876" \| "6078137" \| "6129603").PN.	US-PGPUB; USPAT; USOCR	OR	ON	2006/03/17 12:37
S32	0	("6534912").URPN.	USPAT	OR	ON	2006/03/17 15:51